

## Supporting Information

### Fast Fabrication of SnTe via Non-Equilibrium Method and Enhanced Thermoelectric Properties by Medium-Entropy Engineering

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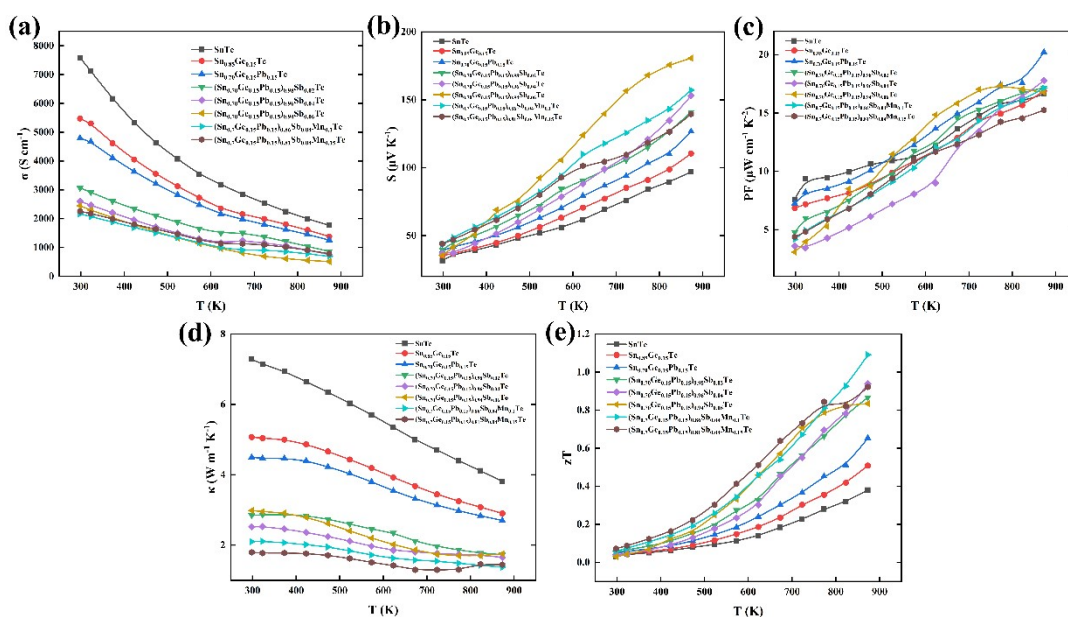


Figure S1. Temperature dependent (a) electrical conductivity, (b) Seebeck coefficient, (c) power factor, (d) thermal conductivity, and (e) zT value.